	Application No.	Applicant(s)	- A
Notice of Allowability	10/708,227	LEE ET AL.	
	Examiner	Art Unit	
	Tonico M. Thomas	2022	
	Toniae M. Thomas	2822	
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate commul GHTS. This application is so	this application. If not include nication will be mailed in due of	d course. <b>THIS</b>
1. This communication is responsive to the election filed on 1	<u>4 July 2004</u> .		
2. The allowed claim(s) is/are 1-18.			
3. The drawings filed on 18 February 2004 are accepted by the	ne Examiner.		
<ul> <li>4.  ☐ Acknowledgment is made of a claim for foreign priority unappriority and a) ☐ All b) ☐ Some* c) ☐ None of the:</li> <li>1. ☐ Certified copies of the priority documents have</li> </ul>		r (f).	
2. Certified copies of the priority documents have		a No	
3. Copies of the certified copies of the priority doc			ion from the
International Bureau (PCT Rule 17.2(a)).	caments have been received	in this national stage applicati	on nom the
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" on noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		a reply complying with the requ	uirements
5. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give	itted. Note the attached EXA es reason(s) why the oath or	MINER'S AMENDMENT or NO declaration is deficient.	OTICE OF
6. CORRECTED DRAWINGS ( as "replacement sheets") mus	t be submitted.		
(a)  including changes required by the Notice of Draftspers	on's Patent Drawing Review	(PTO-948) attached	
1)  hereto or 2)  to Paper No./Mail Date			
(b) including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or	in the Office action of	
Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the	84(c)) should be written on the ne header according to 37 CFF	e drawings in the front (not the laction in the laction).	back) of
7. DEPOSIT OF and/or INFORMATION about the depose attached Examiner's comment regarding REQUIREMENT F	sit of BIOLOGICAL MATE FOR THE DEPOSIT OF BIO	RIAL must be submitted. No LOGICAL MATERIAL.	ote the
Attachment(s)  1.   Notice of References Cited (PTO-892)	5 🗀 Notice of Info	ormal Patent Application (PTO	_152)
2.  Notice of Draftperson's Patent Drawing Review (PTO-948)	6. Interview Su		-132)
3. ⊠ Information Disclosure Statements (PTO-1449 or PTO/SB/0	Paper No./N	Mail Date Amendment/Comment	
Paper No./Mail Date <u>02/18/04</u> 4.  Examiner's Comment Regarding Requirement for Deposit			
of Biological Material	8. ☑ Examiners S	Statement of Reasons for Allow .	vance

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## **EXAMINER'S AMENDMENT**

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# Election/Restrictions

1. Applicant's election **without** traverse of Group I, claims 1-8, in the reply filed on 14 July 2004 is acknowledged.

2. Also, in the reply filed on 14 July 2004, the Applicant cancelled claims 19-24 "without waiver, prejudice or disclaimer," the claims being drawn to a nonelected invention. Since it is believed that Applicant's intention was to cancel all claims belonging to the invention of Group II, claims 19-28 have been cancelled via the examiner's amendment below.<sup>1</sup>

#### **Amendment**

3. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

In Specification

At paragraph 005, line 1, "non-volatile" has been changed to -

--volatile-- after "type of";

At paragraph 0015, line 10, "106" has been changed to --104--

after "mask layer";

<sup>&</sup>lt;sup>1</sup> In the restriction requirement mailed on 18 June 2004, the examiner indicated inadvertently that the invention of Group II includes claims 19-24. However, this is incorrect. The invention of Group II includes claims 19-28.

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At paragraph 0017, line 21, "oneach" has been changed --on each--; At paragraph 0018, line 2, "are" has been changed to --is-after "104"; At paragraph 0018, line 7, "than" has been deleted after "above"; At paragraph 0019, line 5, "serves" has been changed to --serve-- after "126"; At paragraph 0024, line 15, "position" has been changed to --positioned--At paragraph 0024, line 29, "regionadjacent" has been changed to --region adjacent" after "channel".

## In Claims

Claims 19-28 have been cancelled.

### Reasons for Allowance

The following is an examiner's statement of reasons for allowance: the prior art of record fails to anticipate, teach, or suggest – either when considered separately or when combined - a process for fabricating a dynamic random access memory (DRAM) substantially as claimed. For example, the Hsu et al. patent (Hsu) discloses a method for fabricating a DRAM (figs. 7, 8, 9, and col. 3, line 66 – col. 4, line 53). The method comprises the steps of: providing a substrate; forming a plurality of trenches in the substrate; forming a capacitor

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inside each trench; patterning a plurality of active regions on the substrate; forming a plurality of word lines on the substrate; forming a pair of source/drain regions in each active region; and forming a plurality of bit lines over the substrate (fig. 8 and col. 4, lines 23-33). Hsu further discloses: a first side edge of each active region having a first trench whose capacitor is coupled to the active region; and a second side edge of an adjacent active region having a second trench such that a word line passes through both the active region and the second trench, wherein the area in the active region covered by the word line serves as a channel region, and wherein the source/drain regions of each active region are electrically connected to a capacitor and a bit line (fig. 8 and col. 4, lines 23-33). Whereas Hsu discloses forming trenches in the substrate and patterning the active regions, Hsu differs from the claimed invention in that Hsu does not anticipate, teach, or suggest performing an ion implantation tilted at an angle along the word line direction -after forming the trenches, but prior to patterning the active regions - to form a doped region on each side of the channel region in the substrate, such that the dopants within the doped regions have a conductive type identical to that of the substrate. There is no teaching or suggestion within the other prior art references of record to modify Hsu by performing an ion implantation as in the claimed invention.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should

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preferably accompany the issue fee. Such submissions should be clearly

labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Toniae M. Thomas whose telephone number is (571) 272-1846. The examiner can normally be reached on Monday-Thursday from 8:30 a.m. to 5:30 p.m..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on (571) 272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

JMJ

03 September 2004

Mary Wilczewski Primary Evaminar